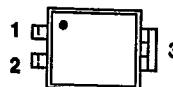


4-PIN DIP  
(Similar to TO-250)

TOP VIEW

## PRODUCT SUMMARY

$V_{(BR)DS}$ (V)	$r_{DS(ON)}$ ( $\Omega$ )	$I_D$ (A)
100	0.60	1.0



1 GATE  
2 SOURCE  
3 DRAIN

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$  Unless Otherwise Noted)

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNITS
Drain-Source Voltage		$V_{DS}$	100	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	
Continuous Drain Current	$T_A = 25^\circ\text{C}$	$I_D$	1.0	A
	$T_A = 100^\circ\text{C}$		0.63	
Pulsed Drain Current <sup>1</sup>		$I_{DM}$	8.0	
Power Dissipation	$T_A = 25^\circ\text{C}$	$P_D$	1.0	W
	$T_A = 100^\circ\text{C}$		0.40	
Operating Junction & Storage Temperature Range		$T_J, T_{stg}$	-55 to 150	$^\circ\text{C}$
Lead Temperature ( $1/16$ " from case for 10 sec.)		$T_L$	300	

4

## THERMAL RESISTANCE RATINGS

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Ambient	$R_{thJA}$		120	K/W

<sup>1</sup>Pulse width limited by maximum junction temperature.

## 2N7004



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ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ\text{C}$  Unless Otherwise Noted)

-39-05

PARAMETER	SYMBOL	TEST CONDITIONS	TYP	LIMITS		UNIT	
				MIN	MAX		
<b>STATIC</b>							
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0\text{ V}, I_D = 250\ \mu\text{A}$		100		V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 1000\ \mu\text{A}$		2.0	4.0		
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$			$\pm 500$	nA	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = V_{(BR)DSS}, V_{GS} = 0\text{ V}$			250	$\mu\text{A}$	
		$V_{DS} = 0.8 \times V_{(BR)DSS}, V_{GS} = 0\text{ V}, T_J = 125^\circ\text{C}$			1000		
On-State Drain Current <sup>1</sup>	$I_{D(on)}$	$V_{DS} = 2\text{ V}, V_{GS} = 10\text{ V}$		1.0		A	
Drain-Source On-State Resistance <sup>1</sup>	$r_{DS(on)}$	$V_{GS} = 10\text{ V}, I_D = 0.8\text{ A}$	0.5		0.60	$\Omega$	
		$V_{GS} = 10\text{ V}, I_D = 0.8\text{ A}, T_J = 125^\circ\text{C}$	0.9		1.1		
Forward Transconductance <sup>1</sup>	$g_{fs}$	$V_{DS} = 15\text{ V}, I_D = 0.8\text{ A}$	0.9	0.8		S	
<b>DYNAMIC</b>							
Input Capacitance	$C_{iss}$	$V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$		170		250	pF
Output Capacitance	$C_{oss}$			75		100	
Reverse Transfer Capacitance	$C_{rss}$			23		40	
Total Gate Charge <sup>2</sup>	$Q_g$	$V_{DS} = 0.5 \times V_{(BR)DSS}, V_{GS} = 10\text{ V}, I_D = 1\text{ A}$		6		7.0	nC
Gate-Source Charge <sup>2</sup>	$Q_{gs}$			1.2			
Gate-Drain Charge <sup>2</sup>	$Q_{gd}$			2.5			
Turn-On Delay Time <sup>2</sup>	$t_{d(on)}$	$V_{DD} = 50\text{ V}, R_L = 62\ \Omega$ $I_D \approx 0.8\text{ A}, V_{GEN} = 10\text{ V}, R_G = 25\ \Omega$		7		20	ns
Rise Time <sup>2</sup>	$t_r$			18		25	
Turn-Off Delay Time <sup>2</sup>	$t_{d(off)}$			24		25	
Fall Time <sup>2</sup>	$t_f$			11		20	
<b>SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (<math>T_A = 25^\circ\text{C}</math>)</b>							
Continuous Current	$I_S$				1.0	A	
Pulsed Current <sup>3</sup>	$I_{SM}$				8.0		
Forward Voltage <sup>1</sup>	$V_{SD}$	$I_F = I_S, V_{GS} = 0\text{ V}$			2.5	V	
Reverse Recovery Time	$t_{rr}$	$I_F = I_S, di_F/dt = 100\text{ A}/\mu\text{s}$	65			ns	
Reverse Recovery Charge	$Q_{rr}$		0.12				$\mu\text{C}$

<sup>1</sup>Pulse test: Pulse Width  $\leq 300\ \mu\text{sec}$ , Duty Cycle  $\leq 2\%$ .<sup>2</sup>Independent of operating temperature.<sup>3</sup>Pulse width limited by maximum junction temperature.



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2N7004

TYPICAL CHARACTERISTICS (25°C Unless Otherwise Specified)

T-39.05

Figure 1. Output Characteristics

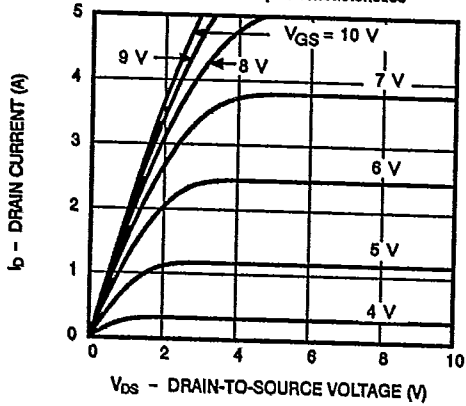


Figure 2. Transfer Characteristics

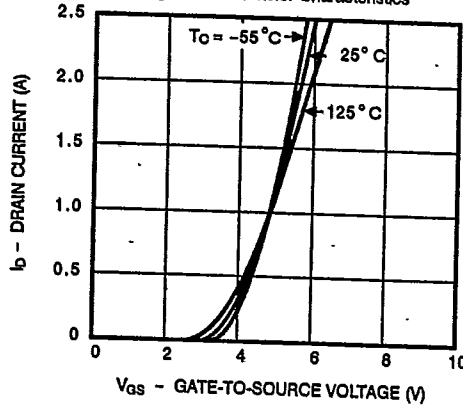


Figure 3. Transconductance

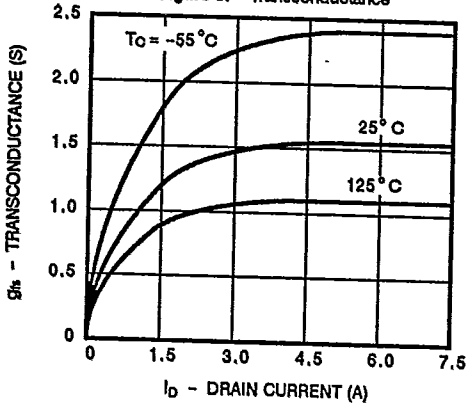
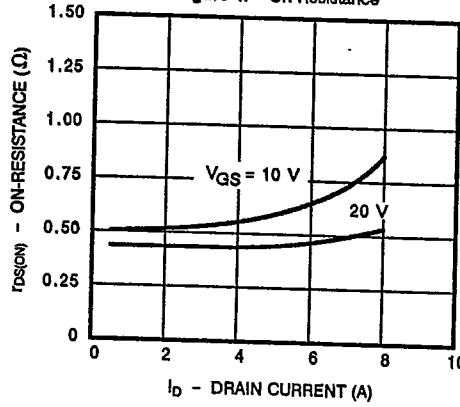


Figure 4. On-Resistance



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Figure 5. Capacitance

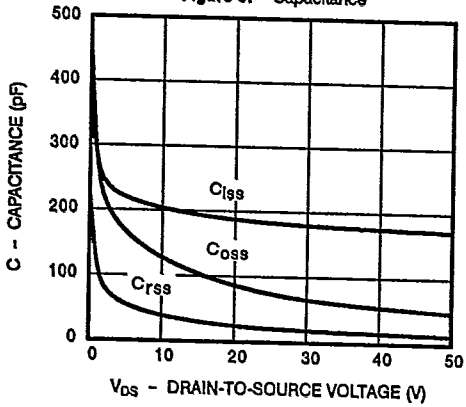
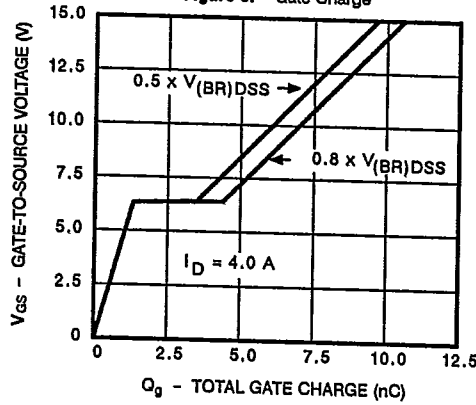


Figure 6. Gate Charge



# 2N7004

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TYPICAL CHARACTERISTICS (Cont'd)

T-39-05

Figure 7. On-Resistance vs. Junction Temperature

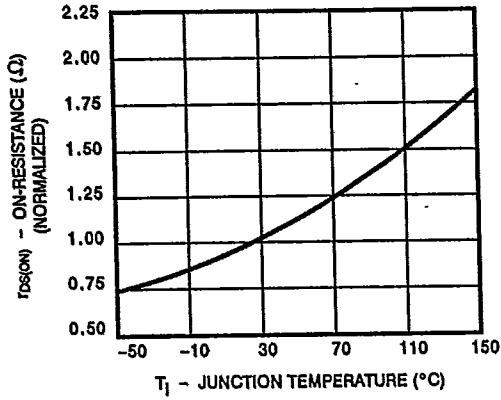
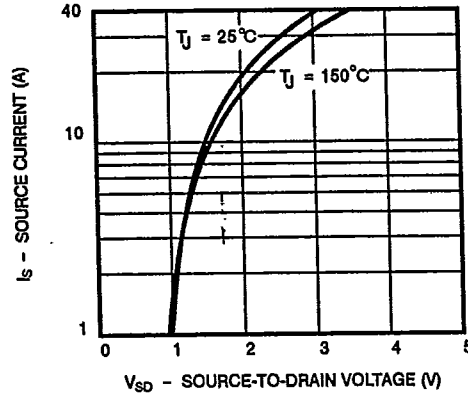


Figure 8. Source-Drain Diode Forward Voltage



THERMAL RATINGS

Figure 9. Maximum Drain Current vs. Case Temperature

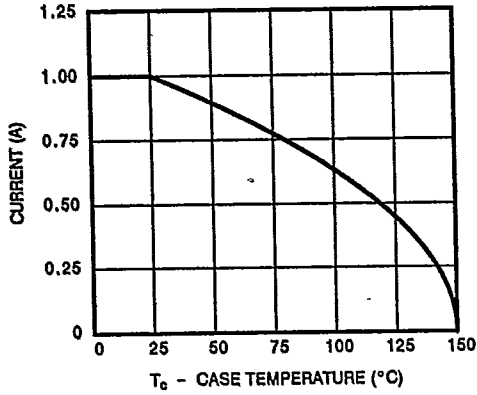


Figure 10. Safe Operating Area

